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# Effect of Ca-doping on the structural and electrical properties of $CuY_{1-x}Ca_xO_2$ ( $0 \le x \le 0.10$ ) ceramics

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#### ABSTRACT

Delafossites  $CuY_{1-x}Ca_xO_2$  ( $0 \le x \le 0.10$ ) ceramics have been prepared by solid state reaction using  $Cu_2O$ ,  $Y_2O_3$  and  $CaCO_3$ . Liquid phase sintering, which obviously accelerates the reaction speed of  $Cu_2O-Y_2O_3-CaCO_3$  system and promotes the formation of  $CuYO_2$  phase is evidenced for the Ca-doped samples. During the sintering process, CuO can react with CaO to form two intermediate compounds,  $CaCu_2O_3$  and  $Ca_2CuO_3$ , which decompose into CaO and liquid phase during 1273-1323 K. In the dopant range of  $0 \le x \le 0.10$ , both electrical conductivity and density of the samples are increased by Ca-doping. The room temperature conductivity of  $CuY_{0.94}Ca_{0.06}O_2$  is more than four orders of magnitude higher than that of  $CuYO_2$ .

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## 1. Introduction

Delafossite oxides ABO<sub>2</sub> (A is Cu and Ag, B is trivalent cation, such as Al, Cr, Y, La, Sc) have been studied intensively due to their applications as catalysts [1–3], sensors [4,5], diluted magnetic semiconductors [6] and transparent p-type conducting oxides (p-TCOs) [7–10]. As the key components of all-oxide transparent devices, the p-TCOs have potential applications in the so called "invisible circuits" [11]. However, the conductivities of these p-TCOs are much lower than those of n-TCOs, such as tin-doped indium oxide (ITO), ZnO [12]. With the aim to enhance p-type conductivities, acceptor-doping on B-site as well as nonstoichiometric (excess oxygen and/or excess metal cations) in these delafossite oxides are interesting to be studied [13–17].

The delafossite structure can be described as sheets of edge-shared  $BO_6$  octahedra alternating stacked with close-packed A-ions layers. Delafossites  $ABO_2$  can form either rhombohedral 3R ( $R\overline{3}m$ ) or hexagonal 2H ( $PG_3$ /mmc) structures, depending on the stacking of the layers [18]. In the previous studies, the crystal structure, luminescence property and thermoelectric power of  $CuYO_2$  were studied; its application to p-TCOs and hydrogen photocathode was explored [19–22].  $Ca^{2+}$  doped  $CuYO_2$  has also been reported

in the previous studies [23-25]. Singh et al. have analyzed the thermopower and related properties of doped CuYO2 and suggested that Ca<sup>2+</sup> doping in the Y site was less likely to produce strong scattering. Study on luminescence properties by Tsuboi et al. showed that for  $CuY_{1-x}Ca_xO_2$  (0  $\leq x \leq$  0.05), with the increase in Ca concentration, the Cu<sup>+</sup> emission shifted slightly to the shorterwavelength side which was considered to be caused by the increase in hole concentration. They have also found that the p-type conductivity of  $CuR_xCa_yY_{1-x-y}O_2$  (x = 0.005 and  $y \le 0.02$ ) increased with increasing Ca concentration, indicating the increase of hole concentration caused by doping with  $Ca^{2+}$  acceptor cation on the  $Y^{3+}$  site. Ingram has reported significant increase in the hole concentration of CuY<sub>0.95</sub>Ca<sub>0.05</sub>O<sub>2</sub> relative to the undoped compound, however the hole contents were less than expected based upon the doping level, second phases (e.g., CaO) were assumed to exist in small proportions though they were undetectable in XRD analysis.

It is reported that the Ca<sup>2+</sup> doped CuYO<sub>2</sub> thin film prepared by thermal co-evaporation showed a bandgap of 3.5 eV, average transparency of 50% in the visible region and enhanced p-type conductivity of 1.0 S cm<sup>-1</sup>.

In this article, a series of  $CuY_{1-x}Ca_xO_2$  ( $0 \le x \le 0.10$ ) ceramics were prepared by solid-state reaction technique using  $Cu_2O$ ,  $Y_2O_3$  and  $CaCO_3$ . The role of  $CaCO_3$  in the reaction system of  $Cu_2O-Y_2O_3-CaCO_3$  was studied. The effect of Ca-doping on the structural and electrical properties of  $CuYO_2$  was investigated.

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#### 2. Experimental

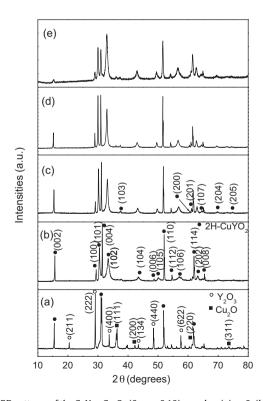
Polycrystalline samples of delafossites  $CuY_{1-x}Ca_xO_2$  ( $0 \le x \le 0.10$ ) were prepared by solid-state reaction technique. The starting materials were  $Cu_2O$  (Alfa Aesar, 99.0%),  $Y_2O_3$  (Alfa Aesar, 99.9%) and  $CaCO_3$  (Alfa Aesar, 99.0%).  $Y_2O_3$  was dried at 1073 K under air atmosphere for 8 h before use. The stoichiometric mixtures of  $Cu_2O$ ,  $Y_2O_3$  and  $CaCO_3$  were grinded and sintered at 1373 K for 10 h under  $N_2$  atmosphere, respectively. The grinding and sintering procedures were repeated twice. Then the powders were grinded, pelleted and annealed at 1373 K for 10 h under  $N_2$  atmosphere, respectively, to obtain pure delafossite phase. Note that the  $N_2$  gas stream was cut off when all the samples were cooled to 473 K. All the pellets were pressed under the same pressure of about 35 MPa and annealed in a batch in order to exclude the influence of experimental factors on the electrical properties.

A Philips X'pert PRO X-ray diffractometer (XRD) with  $\hat{C}u$ -K $\alpha$  source was used to identify the crystalline phases. Diffraction patterns were taken from 10 to  $80^\circ$  at a scanning speed of  $4^\circ$ /min. The lattice parameters were calculated by the least square method from the diffraction peaks (002), (100), (101), (004), (102), (104), (110), (106) and (114) of the 2H-CuYO2 phase. The theoretical densities were calculated from the lattice parameters. Though the absolute value of the lattice parameters and theoretical densities may not be accurate, the relative variations of the parameters could provide valuable information.

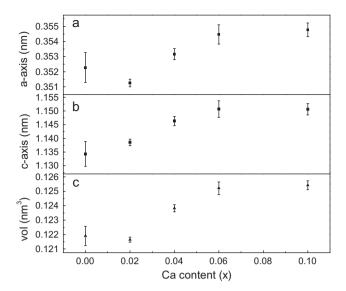
A FEI designed Sirion 200 field-emission scanning electron microscope (FE-SEM) was used to check the crystallization and microstructures. The temperature dependence of the conductivity was measured by the standard four-probe method by means of the cryogenic refrigeration equipment.

## 3. Results and discussion

XRD analysis was performed on the  $\text{CuY}_{1-x}\text{Ca}_x\text{O}_2$  ( $0 \le x \le 0.10$ ) samples which were prepared under the same sintering temperature of 1373 K for 20 h. For the samples of  $0.02 \le x \le 0.10$ , all diffraction peaks are indexed as the 2H–CuYO $_2$  phase (JCPDF No. 76-1422) and no secondary phase can be detected, as shown in Fig. 1. For the sample of x=0, the diffraction peaks of original material  $Y_2O_3$  can be found. Further sintering the sample at 1453 K for 10 h still can detect some  $Y_2O_3$  phase. This means that CaCO $_3$  can obviously accelerate the reaction speed of the Cu $_2O$  and  $Y_2O_3$ , and then decrease the sintering temperature of CuYO $_2$ . In addition, the gradual shifting to lower angle was observed on the XRD pattern peaks for the calcium doped samples. That may be associated with the



**Fig. 1.** XRD patterns of the  $CuY_{1-x}Ca_xO_2$  ( $0 \le x \le 0.10$ ) samples: (a) x = 0; (b) x = 0.02; (c) x = 0.04; (d) x = 0.06; (e) x = 0.10.

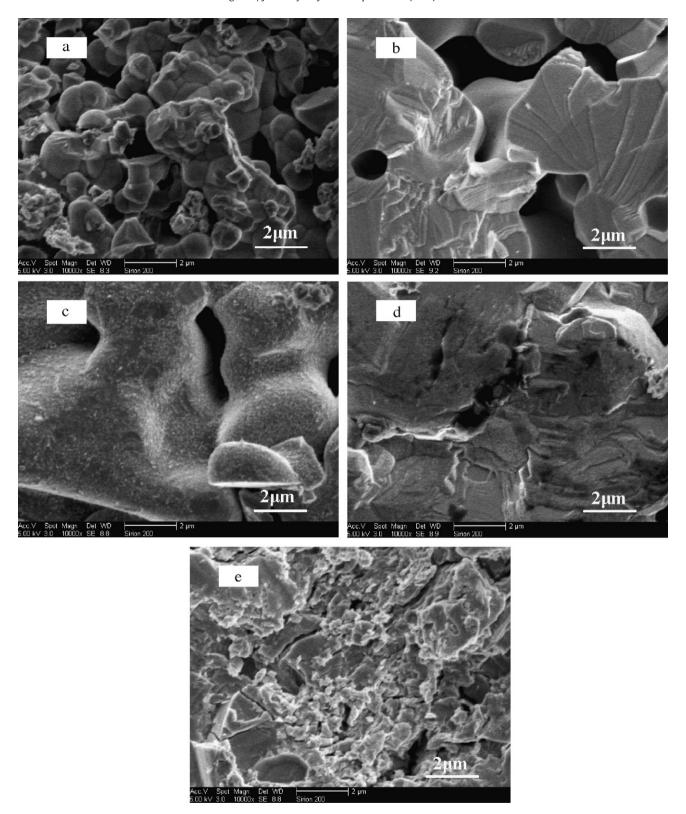


**Fig. 2.** Lattice parameters of the  $CuY_{1-x}Ca_xO_2$  ( $0 \le x \le 0.10$ ) samples.

solid solution of  $Ca^{2+}$  into the  $CuYO_2$  lattice, due to the substitution of  $Ca^{2+}$  ions with a large ionic radius (0.99 Å) for  $Y^{3+}$  (0.89 Å). Indeed, the lattice parameters (Fig. 2) obtained from XRD patterns increase with the Ca-doping amounts x for  $0 \le x \le 0.06$ , but further increase of the x makes negligible elongation of the lattice parameters suggesting a solubility limit of 0.06, which agrees with the inference proposed above. Secondary phases (e.g., CaO) may be undetectable by XRD analysis, but are assumed to exist in small proportions in the sample of x = 0.10. For sample x = 0, some diffraction peaks of original material  $Y_2O_3$  may overlap with that of 2H– $CuYO_2$  and result in larger error than those of other samples in lattice parameters calculation. That may be the reason for the lattice parameters decrease from x = 0 to 0.02.

SEM analysis was performed to check the microstructures, as shown in Fig. 3. The particles of the undoped sample exhibit an irregular morphology consisting of particles around 1  $\mu$ m with some agglomeration, as shown in the Fig. 3(a). The morphologies of the Ca-doped samples, which are absolutely different from the undoped sample with much larger particles compactly connected to each other, suggest liquid phase sintering taking place. The liquid phase sintering obviously accelerates the reaction speed of Cu<sub>2</sub>O–Y<sub>2</sub>O<sub>3</sub>–CaCO<sub>3</sub> system and promotes the formation of CuYO<sub>2</sub> phase. It also contributes to the increase of relative density from about 67% for the undoped sample to around 80% for the Ca-doped samples.

Since the liquid phase may be obtained by the reaction of system CaCO<sub>3</sub>-Cu<sub>2</sub>O or Y<sub>2</sub>O<sub>3</sub>-CaCO<sub>3</sub> at 1373 K, a series of experiments were designed to figure out the origin of liquid phase, as shown in Table 1. Cu<sub>2</sub>O-Y<sub>2</sub>O<sub>3</sub> (labeled as S2), CaCO<sub>3</sub>-Y<sub>2</sub>O<sub>3</sub> (labeled as S3) and CaCO3-Cu2O (labeled as S4) were sintered at 1323 K under N<sub>2</sub> atmosphere, respectively. Only sample S4, which is mainly composed of CaO and Cu<sub>2</sub>O phases, shows the sign of liquid phase sintering as shown in Figs. 4 and 5. Gadalla [26] and Hou [27] reported that in the system CuO-Cu<sub>2</sub>O-CaO (CaCO<sub>3</sub>), CaCO<sub>3</sub> decomposed completely into CaO and CO<sub>2</sub> below 1073 K, then CuO and CaO could react to form two intermediate compounds, CaCu<sub>2</sub>O<sub>3</sub> and Ca<sub>2</sub>CuO<sub>3</sub>, which decomposed into CaO and liquid phase during 1273-1323 K. Under the reduced oxygen condition of our experiments, the formation of CaCu2O3 and Ca2CuO3 is also evidenced in the system CaCO<sub>3</sub>-Cu<sub>2</sub>O at 1123 K (labeled as S5) as shown in Fig. 6. The formation of liquid phase during the sintering process obviously accelerates the formation of CuYO<sub>2</sub> phase and decreases the porosity.



**Fig. 3.** SEM images of the  $CuY_{1-x}Ca_xO_2$  ( $0 \le x \le 0.10$ ) samples: (a) x = 0; (b) x = 0.02; (c) x = 0.04; (d) x = 0.06; (e) x = 0.10.

The temperature dependences of electrical conductivities are shown in Fig. 7. Electrical conductivities increase with the increase of temperature over the measured temperature range, indicating semiconducting behavior. It is reported that Ca-doping could enhance the electrical conductivity of CuYO<sub>2</sub> by introducing positive holes [19,21,23–25,28]. In our experiment, the conductiv-

ities increase with the dopant concentration x when  $0 \le x \le 0.06$  and then decrease with x when  $0.06 \le x \le 0.10$ , which may be ascribed to second phase formation. Moreover, it is observed that the room temperature conductivity of the sample with x = 0.06  $(5.11 \times 10^{-3} \, \text{S cm}^{-1})$  is more than four orders of magnitude higher than that of the sample with x = 0  $(1.18 \times 10^{-7} \, \text{S cm}^{-1})$ .

**Table 1** Sintering conditions of samples S1–S5.

No.	Starting materials	Molar ratio	Reaction conditions	Liquid phase sintering?
S1	$Cu_2O-Y_2O_3-CaCO_3$	Cu:Y:Ca = 1:0.9:0.1	1323 K, N <sub>2</sub> , 12 h	Yes
S2	$Cu_2O-Y_2O_3$	Cu:Y = 1:1	1323 K, N <sub>2</sub> , 12 h	No
S3	$CaCO_3-Y_2O_3$	Ca:Y = 1:1	1323 K, N <sub>2</sub> , 12 h	No
S4	CaCO <sub>3</sub> -Cu <sub>2</sub> O	Ca:Cu = 1:1	1323 K, N <sub>2</sub> , 12 h	Yes
S5	CaCO <sub>3</sub> -Cu <sub>2</sub> O	Ca:Cu = 1:1	1123 K, N <sub>2</sub> , 12 h	No

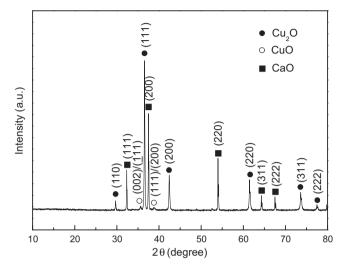


Fig. 4. XRD pattern of sample S4.

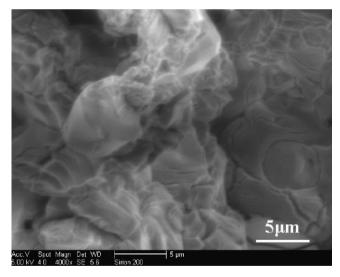


Fig. 5. SEM image of sample S4.

## 4. Conclusions

The effect of Ca-doping on the structural and electrical properties of CuYO<sub>2</sub> ceramics is studied. By introducing CaCO<sub>3</sub> into the system Cu<sub>2</sub>O-Y<sub>2</sub>O<sub>3</sub>, intermediate liquid phase is formed by the reaction of Cu<sub>2</sub>O and CaO during the sintering process, which obviously accelerates the reaction speed of Cu<sub>2</sub>O-Y<sub>2</sub>O<sub>3</sub>-CaCO<sub>3</sub> system and promotes the formation of CuYO<sub>2</sub> phase, the porosity is decreased as well. Significant enhancement of conductivities in the dopant range  $0 \le x \le 0.10$  is also observed. The room temperature conductivity of the sample with x = 0.06 is more than four orders of magnitude higher than that of the sample with x = 0.

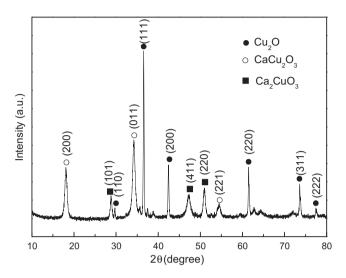
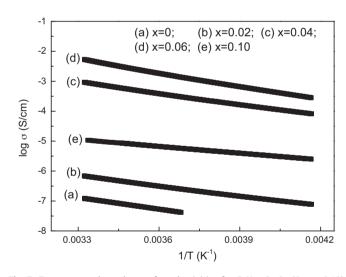


Fig. 6. XRD pattern of sample S5.



**Fig. 7.** Temperature dependence of conductivities for  $CuY_{1-x}Ca_xO_2$  ( $0 \le x \le 0.10$ ) samples: (a) x = 0; (b) x = 0.02; (c) x = 0.04; (d) x = 0.06; (e) x = 0.10.

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## References

- [1] S. Kato, R. Fujimaki, M. Ogasawara, T. Wakabayashi, Y. Nakahara, S. Nakata, Appl. Catal. B-Environ. 89 (2009) 183–188.
- [2] W. Ketir, A. Bouguelia, M. Trari, Desalination 244 (2009) 144–152.

- [3] H. Dong, Z. Li, X. Xu, Z. Ding, L. Wu, X. Wang, X. Fu, Appl. Catal. B-Environ. 89 (2009) 551–556.
- [4] S. Zhou, X.D. Fang, Z.H. Deng, D. Li, W.W. Dong, R.H. Tao, G. Meng, T. Wang, Sensor. Actuators B-Chem. 143 (2009) 119–123.
- [5] Z.H. Deng, X.D. Fang, D. Li, S. Zhou, R.H. Tao, W.W. Dong, T. Wang, G. Meng, X.B. Zhu, J. Alloys Compd. 484 (2009) 619–621.
- [6] D. Li, X.D. Fang, W.W. Dong, Z.H. Deng, R.H. Tao, S. Zhou, J.M. Wang, T. Wang, Y.P. Zhao, X.B. Zhu, J. Phys. D: Appl. Phys. 42 (2009) 055009–55016.
- [7] P.W. Sadik, M. Ivill, V. Craciun, D.P. Norton, Thin Solid Films 517 (2009) 3211–3215.
- [8] H.F. Jiang, H.C. Lei, X.B. Zhu, G. Li, Z.R. Yang, W.H. Song, J.M. Dai, Y.P. Sun, Y.K. Fu, J. Alloys Compd. 487 (2009) 404–408.
- [9] A.S. Reddy, H.H. Park, G.M. Rao, S. Uthanna, P.S. Reddy, J. Alloys Compd. 474 (2009) 401–405.
- [10] D. Li, X.D. Fang, A.W. Zhao, Z.H. Deng, W.W. Dong, R.H. Tao, Vacuum 84 (2010) 851–856.
- [11] G. Thomas, Nature 389 (1997) 907-908.
- [12] C.E. Benouis, M. Benhaliliba, A. Sanchez Juarez, M.S. Aida, F. Chami, F. Yakuphanoglu, J. Alloys Compd. 490 (2010) 62–67.
- [13] D. Li, X.D. Fang, Z.H. Deng, W.W. Dong, R.H. Tao, S. Zhou, J.M. Wang, T. Wang, Y.P. Zhao, X.B. Zhu, J. Alloys Compd. 486 (2009) 462–467.
- [14] Z.H. Deng, X.D. Fang, R.H. Tao, W.W. Dong, D. Li, X.B. Zhu, Chin. J. Semiconduct. 29 (2008) 1052–1056.

- [15] H.F. Jiang, X.B. Zhu, H.C. Lei, G. Li, Z.R. Yang, W.H. Song, J.M. Dai, Y.P. Sun, Y.K. Fu, J. Alloys Compd. 509 (2011) 1768–1773.
- [16] E. Mugnier, A. Barnabé, P. Tailhades, Solid State Ionics 177 (2006) 607–612.
- [17] R. Kykyneshi, B.C. Nielsen, J. Tate, J. Li, A.W. Sleight, J. Appl. Phys. 96 (2004) 6188–6194.
- [18] M. Beekman, J. Salvador, X. Shi, G.S. Nolas, J. Yang, J. Alloys Compd. 489 (2010) 336–338.
- [19] R.L. Hoffman, J.F. Wager, M.K. Jayaraj, J. Tate, J. Appl. Phys. 90 (2001) 5763– 5767.
- [20] K. Isawa, M. Nagano, K. Yamada, J. Cryst. Growth 237-239 (2002) 783-786.
- [21] N. Tsuboi, H. Ohara, T. Hoshino, S. Kobayashi, K. Kato, F. Kaneko, Jpn. J. Appl. Phys. 44 (2005) 765–768.
- [22] G.V. Tendeloo, O. Garlea, C. Darie, C.B. Chaillout, P. Bordet, J. Solid State Chem. 156 (2001) 428–436.
- [23] D.J. Singh, Phys. Rev. B 77 (2008) 205126-205135.
- [24] N. Tsuboi, T. Hoshino, S. Kobayashi, K. Kato, F. Kaneko, Phys. Status Solidi A 203 (2006) 2723–2728.
- [25] B.J. Ingram, B.J. Harder, N.W. Hrabe, T.O. Mason, K.R. Poeppelmeier, Chem. Mater. 16 (2004) 5623–5629.
- [26] A.M.M. Gadalla, J. White, Br. Ceram. Trans. 62 (1963) 181-190.
- [27] G.H. Hou, X.D. Shen, Z.Z. Xu, J. Chin. Ceram. Soc. 33 (2005) 109–114.
- [28] M. Trari, A. Bouguelia, Y. Bessekhouad, Sol. Energy Mater. Sol. Cells 90 (2006) 190–202.